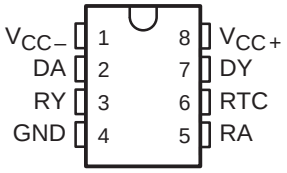
SLLS017C – JULY 1986 – REVISED MAY 1995

- **Meets or Exceeds the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28**
- **10-mA Current Limited Output**
- **Wide Range of Supply Voltage**
  V_{CC} = 4.5 V to 15 V
- **Low Power . . . 130 mW**
- **Built-In 5-V Regulator**
- **Response Control Provides:**
  Input Threshold Shifting
  Input Noise Filtering
- **Power-Off Output Resistance . . . 300 Ω Typ**
- **Driver Input TTL Compatible**

D OR P PACKAGE
TOP VIEW

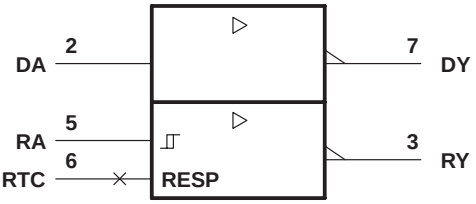


description

The SN75155 monolithic line driver and receiver is designed to satisfy the requirements of the standard interface between data terminal equipment and data communication equipment as defined by ANSI EIA/TIA-232-E. A response control input is provided for the receiver. A resistor or a resistor and a bias voltage can be connected between the response control input and ground to provide noise filtering. The driver used is similar to the SN75188. The receiver used is similar to the SN75189A.

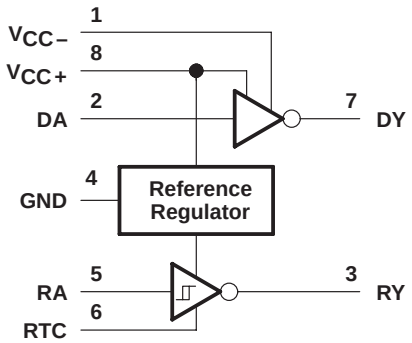
The SN75155 is characterized for operation from 0°C to 70°C.

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12

logic diagram



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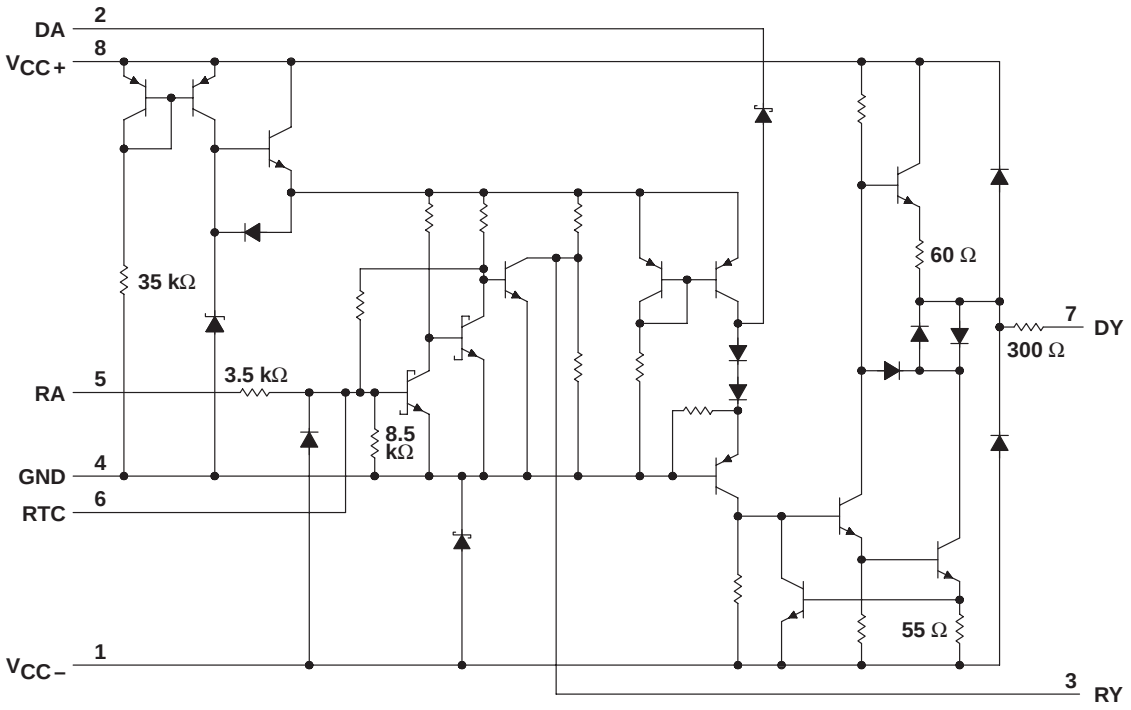
schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC+} (see Note 1) . . . . . 15 V
Supply voltage, V_{CC-} (see Note 1) . . . . . –15 V
Input voltage range, V_I: Driver . . . . . –15 V to 15 V
Receiver . . . . . –30 V to 30 V
Output voltage range (driver), V_O . . . . . –15 V to 15 V
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW
P	1000 mW	8.0 mW/°C	640 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC+}	4.5	12	15	V
Supply voltage, V_{CC-}	−4.5	−12	−15	V
Output voltage, driver, $V_{O(D)}$			±15	V
Input voltage, receiver, $V_{I(R)}$	−25		25	V
High-level input voltage, driver, V_{IH}	2			V
Low-level input voltage, driver, V_{IL}			0.8	V
Response control current			±5.5	mA
Output current, receiver, $I_{O(R)}$			24	mA
Operating free-air temperature, T_A	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

total device

PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
I_{CCH+}	High-level supply current	V_{CC+} = 5 V,	V_{CC-} = −5 V	$V_{I(D)}$ = 2 V, $V_{I(R)}$ = 2.3 V, Output open		6.3	8.1	mA
		V_{CC+} = 9 V,	V_{CC-} = −9 V			9.1	11.9	
		V_{CC+} = 12 V,	V_{CC-} = −12 V			10.4	14	
I_{CCL+}	Low-level supply current	V_{CC+} = 5 V,	V_{CC-} = −5 V	$V_{I(D)}$ = 0.8 V, $V_{I(R)}$ = 0.6 V, Output open		2.5	3.4	mA
		V_{CC+} = 9 V,	V_{CC-} = −9 V			3.7	5.1	
		V_{CC+} = 12V,	V_{CC-} = −12 V			4.1	5.6	
I_{CC+}	Supply current	V_{CC+} = 5 V,	V_{CC-} = 0	$V_{I(R)}$ = 2.3 V, $V_{I(D)}$ = 0		4.8	6.4	mA
		V_{CC+} = 9 V,	V_{CC-} = 0			6.7	9.1	
I_{CCH-}	High-level supply current	V_{CC+} = 5 V,	V_{CC-} = −5 V	$V_{I(D)}$ = 2 V, $V_{I(R)}$ = 2.3 V Output open		−2.4	−3.1	mA
		V_{CC+} = 9 V,	V_{CC-} = −9 V			−3.9	−4.9	
		V_{CC+} = 12 V,	V_{CC-} = −12 V			−4.8	−6.1	
I_{CCL-}	Low-level supply current	V_{CC+} = 5 V,	V_{CC-} = −5 V	$V_{I(D)}$ = 0.8 V, $V_{I(R)}$ = 0.6 V, Output open		−0.2	−0.35	mA
		V_{CC+} = 9 V,	V_{CC-} = −9 V			−0.25	−0.4	
		V_{CC+} = 12 V,	V_{CC-} = −12 V			−0.27	−0.45	

† All typical values are at T_A = 25°C.

electrical characteristics over recommended operating free-air temperature range, V_{CC+} = 12 V, V_{CC-} = –12 V (unless otherwise noted)

driver section

PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
V_{OH}	High-level output voltage	V_{IL} = 0.8 V, R_L = 3 kΩ	V_{CC+} = 5 V,	V_{CC-} = –5 V	3.2	3.7		V
			V_{CC+} = 9 V,	V_{CC-} = –9 V	6.5	7.2		
			V_{CC+} = 12 V,	V_{CC-} = –12 V	8.9	9.8		
V_{OL}	Low-level output voltage (see Note 2)	V_{IH} = 2 V, R_L = 3 kΩ	V_{CC+} = 5 V,	V_{CC-} = –5 V		–3.6	–3.2	V
			V_{CC+} = 9 V,	V_{CC-} = –9 V		–7.1	–6.4	
			V_{CC+} = 12 V,	V_{CC-} = –12 V		–9.7	–8.8	
I_{IH}	High-level input current	V_I = 7 V					5	μA
I_{IL}	Low-level input current	V_I = 0				–0.73	–1.2	mA
$I_{OS(H)}$	High-level short-circuit output current	V_I = 0.8 V, V_O = 0			–7	–12	–14.5	mA
$I_{OS(L)}$	Low-level short-circuit output current	V_I = 2 V, V_O = 0			6.5	11.5	15	mA
r_O	Output resistance with power off	V_O = –2 V to 2 V				300		Ω

receiver section (see Figure 1)

PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
V_{IT+}	Positive-going input threshhold voltage				1.2	1.9	2.3	V
V_{IT-}	Negative-going input threshhold voltage				0.6	0.95	1.2	V
V_{hys}	Hystresis voltage ($V_{IT+} - V_{IT-}$)				0.6			V
$V_{O(H)}$	High-level output voltage	V_I = 0.6 V, I_{OH} = 10 μA	V_{CC+} = 5 V,	V_{CC-} = –5 V	3.7	4.1	4.5	V
			V_{CC+} = 12 V,	V_{CC-} = –12 V	4.4	4.7	5.2	
		V_I = 0.6 V, I_{OH} = 0.4 mA	V_{CC+} = 5 V,	V_{CC-} = –5 V	3.1	3.4	3.8	
			V_{CC+} = 12 V,	V_{CC-} = –12 V	3.6	4	4.5	
$V_{O(L)}$	Low-level output voltage	V_I = 2.3 V, I_{OL} = 24 mA				0.2	0.3	V
I_{IH}	High-level input current	V_I = 2 5 V			3.6	6.7	10	mA
		V_I = 3 V			0.43	0.67	1	mA
I_{IL}	Low-level input current	V_I = –25 V			–3.6	–6.7	–10	mA
		V_I = –3 V			–0.43	–0.67	–1	mA
I_{OS}	Short-circuit output current	V_I = 0.6 V				–2.8	–3.7	mA

† All typical values are at T_A = 25°C.

NOTE 2: The algebraic limit system, in which the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic voltage levels only (e.g., if –8.8 V is the maximum, the typical value is a more negative value).

switching characteristics over recommended operating free-air temperature range, V_{CC+} = 5 V, V_{CC-} = – 5 V, C_L = 50 pF (unless otherwise noted)

driver section (see Figure 2)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high level output	R_L = 3 kΩ		250	480	ns
t_{PHL}	Propagation delay time, high- to low level output			80	150	
t_r	Output rise time	R_L = 3 kΩ		67	180	ns
		R_L = 3 kΩ to 7 kΩ, C_L = 2500 pF		2.4	3	µs
t_f	Output fall time	R_L = 3 kΩ		48	160	ns
		R_L = 3 kΩ to 7 kΩ, C_L = 2500 pF		1.9	3	µs

receiver section (see Figure 3)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high level output	R_L = 400 Ω		175	245	ns
t_{PHL}	Propagation delay time, high- to low level output			37	100	
t_r	Output rise time	R_L = 400 Ω		255	360	ns
t_f	Output fall time	R_L = 400 Ω		23	50	ns

† All typical values are at T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION

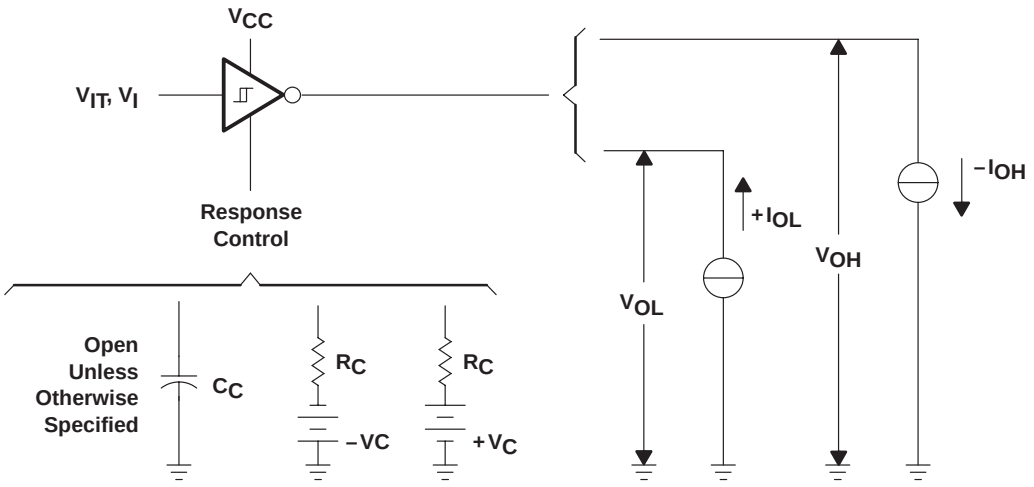
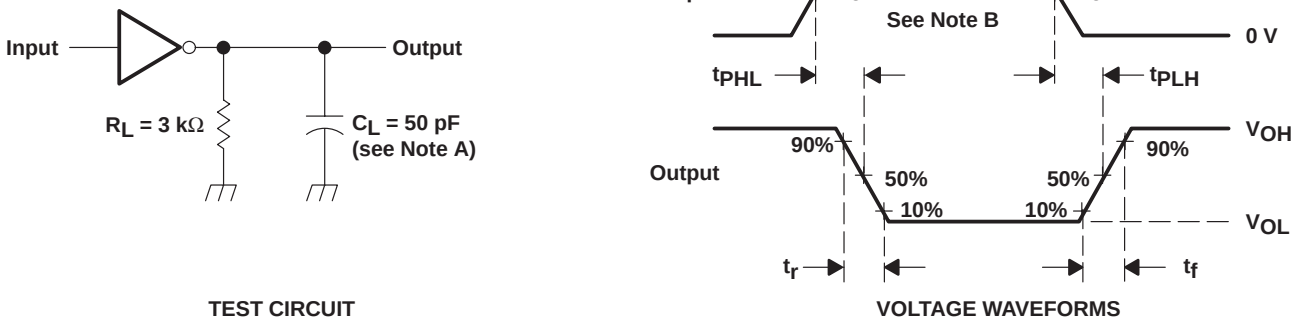


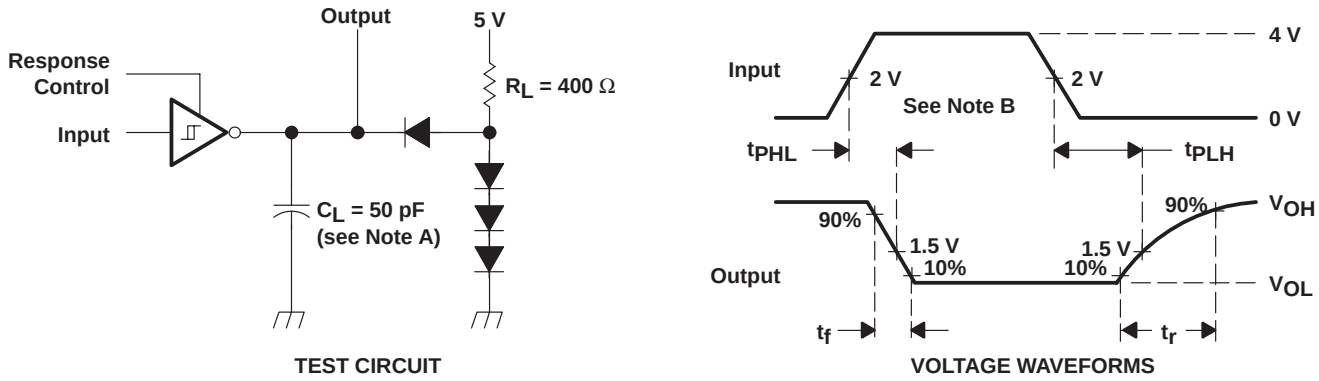
Figure 1. Receiver Section Test Circuit (V_{IT+}, V_{IT-}, V_{OH}, V_{OL})

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.
B. The input waveform is supplied by a generator with the following characteristics: Z_O = 50 Ω, t_W = 1 µs, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 2. Driver Section Switching Test Circuit and Voltage Waveforms



NOTES: A. C_L includes probe and jig capacitance.
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Figure 3. Receiver Section Switching Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

DRIVER
VOLTAGE TRANSFER CHARACTERISTICS

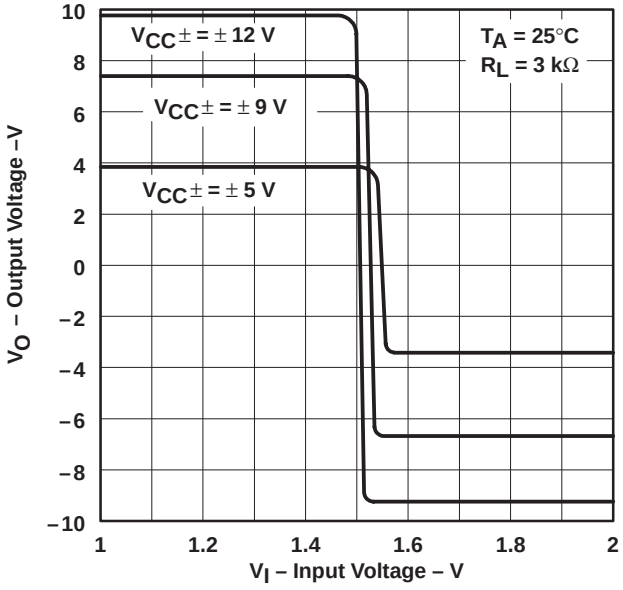

Figure 4

DRIVER
OUTPUT CURRENT
vs
OUTPUT VOLTAGE

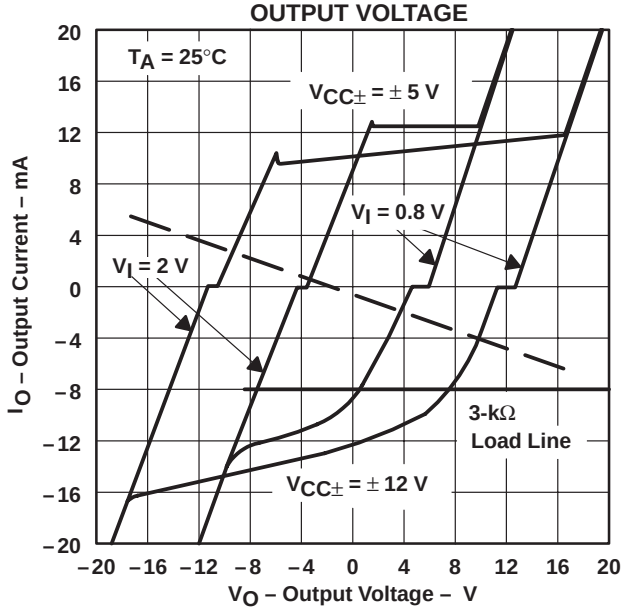

Figure 5

DRIVER
SHORT-CIRCUIT OUTPUT CURRENT
vs
FREE-AIR TEMPERATURE

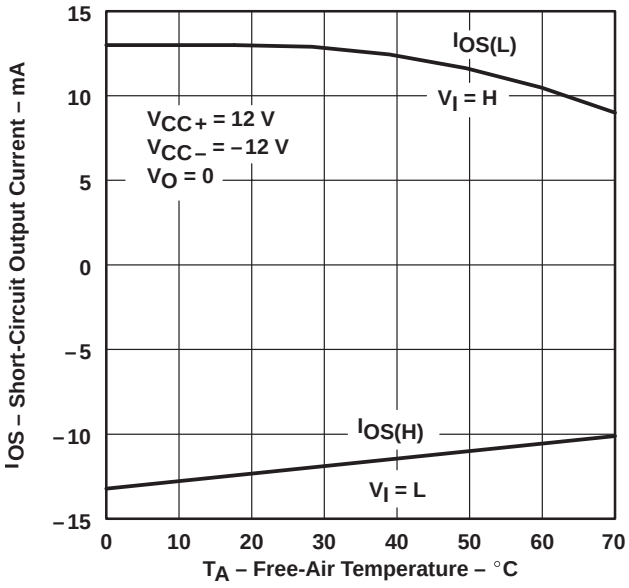

Figure 6

DRIVER
SLEW RATE
vs
LOAD CAPACITANCE

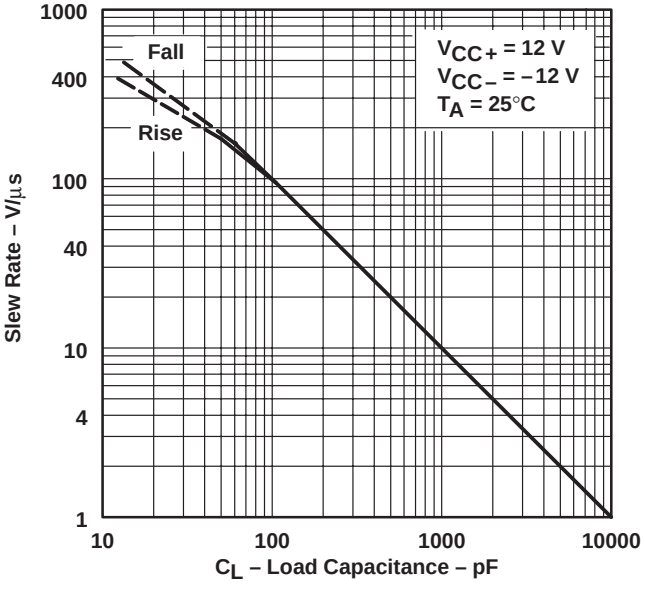

Figure 7

TYPICAL CHARACTERISTICS

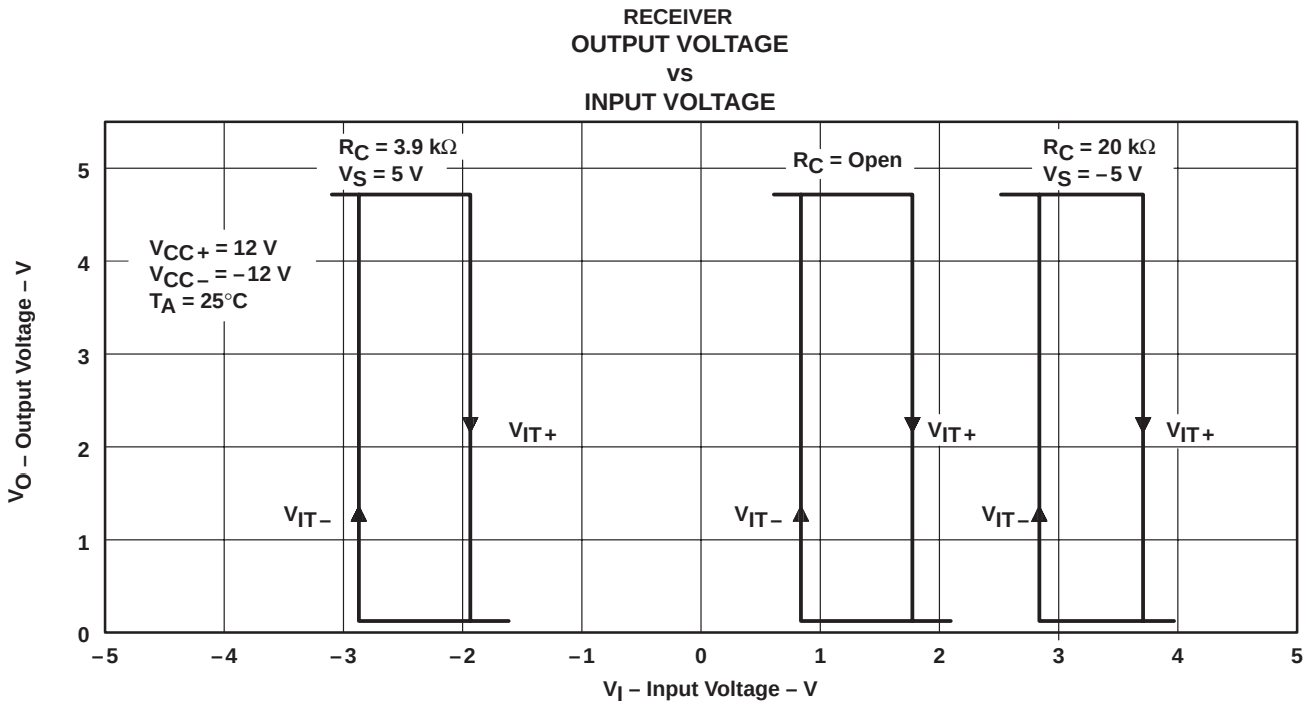

Figure 8

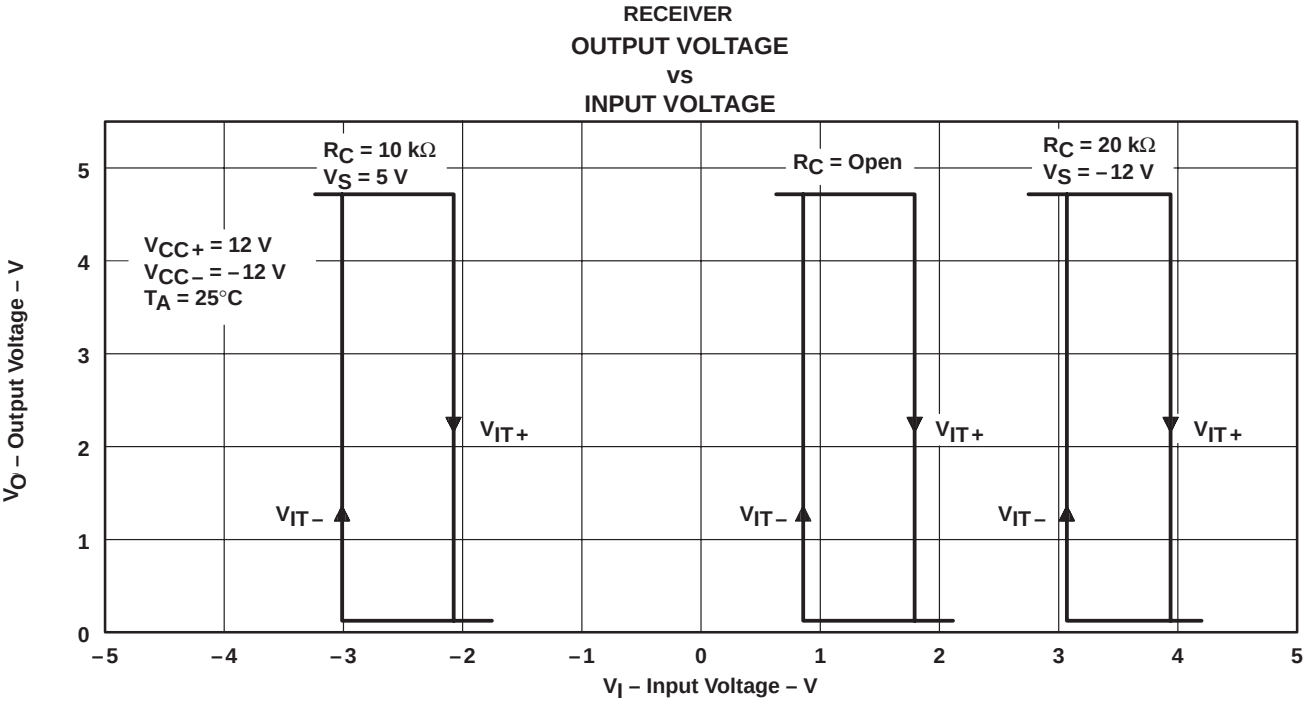

Figure 9

TYPICAL CHARACTERISTICS

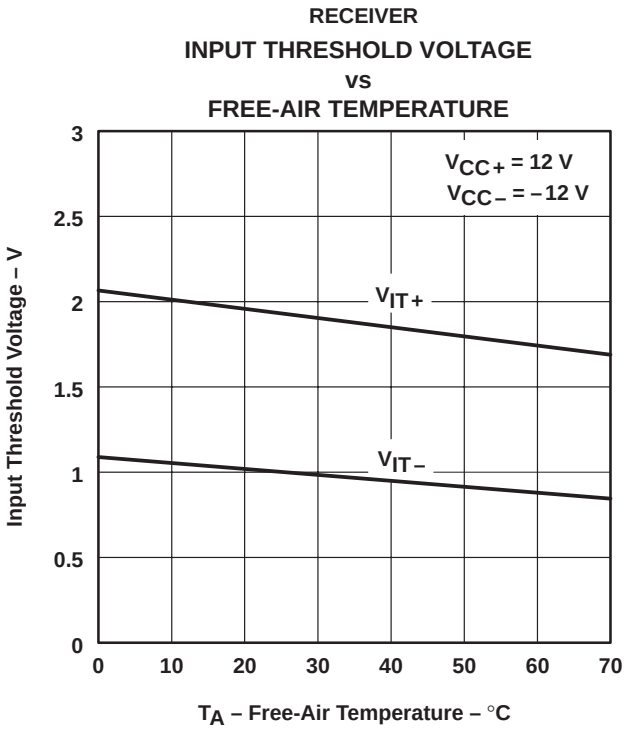

Figure 10

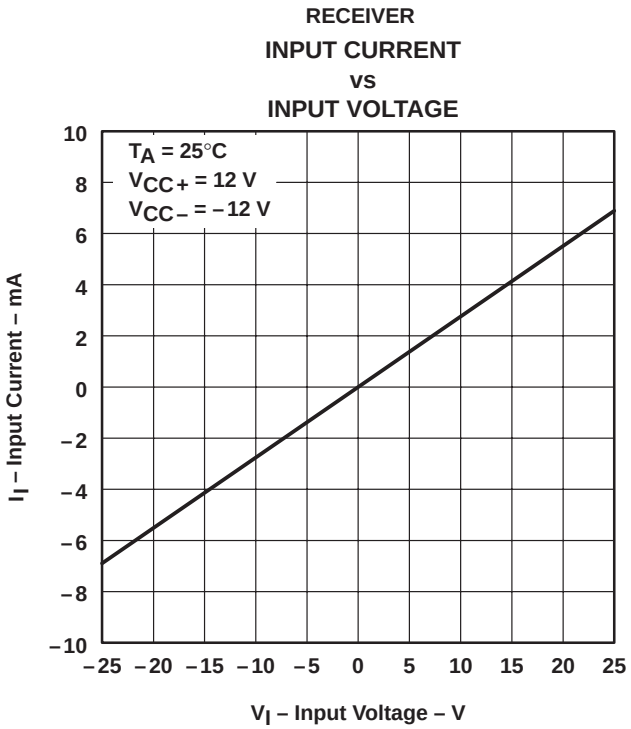

Figure 11

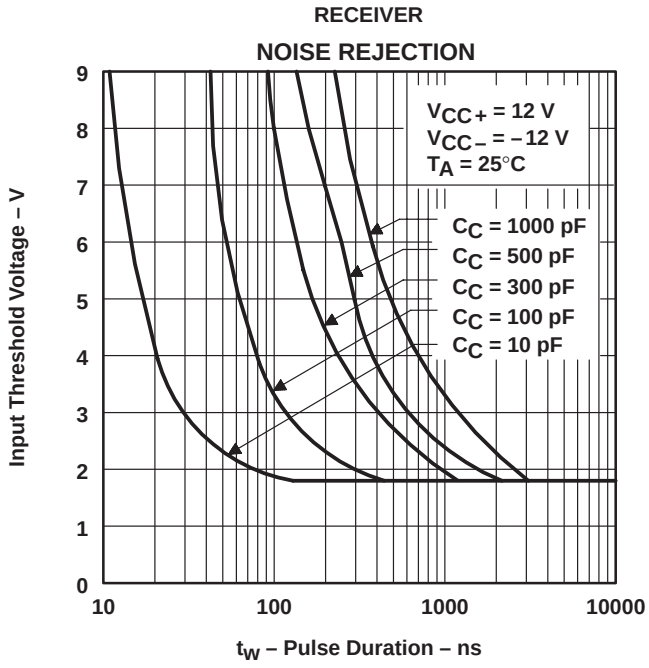

Figure 12

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